

## Power Schottky rectifier

### Features

- High junction temperature capability
- Optimized trade-off between leakage current and forward voltage drop
- Low leakage current
- Avalanche capability specified
- Insulated package TO-220FPAB
  - insulated voltage: 2000 V
  - package capacitance: 45 pF

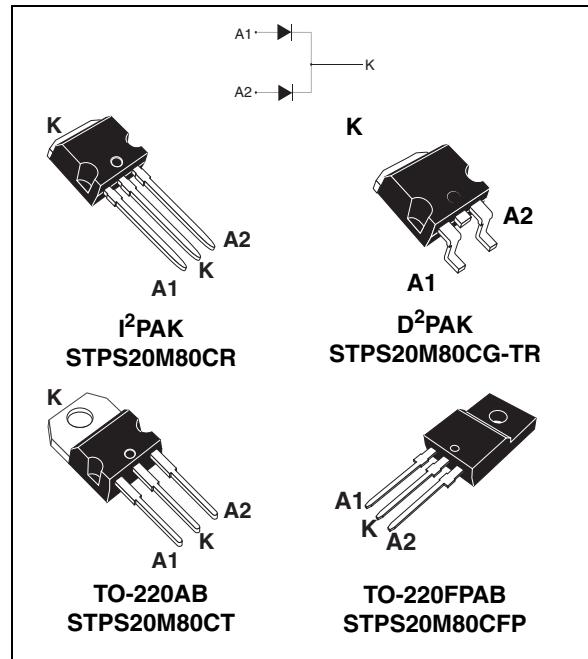
### Description

This dual diode Schottky rectifier is suited for high frequency switch mode power supply.

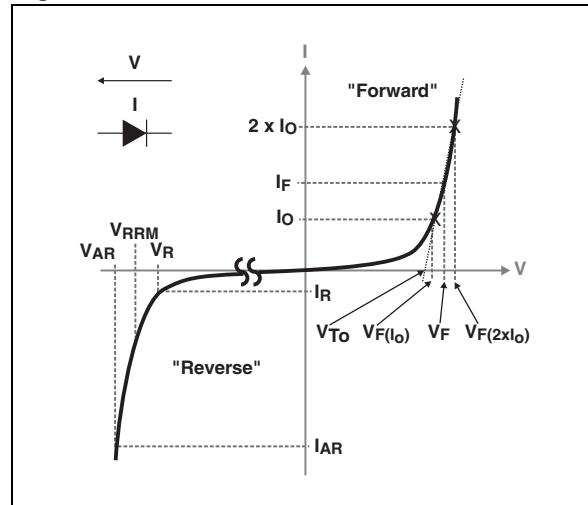
Packaged in TO-220AB, I<sup>2</sup>PAK, D<sup>2</sup>PAK and TO-220FPAB, this device is particularly suited for use in notebook, game station, LCD TV and desktop adapters, providing these applications with a good efficiency at both low and high load.

**Table 1. Device summary**

Symbol	Value
I <sub>F(AV)</sub>	2 x 10 A
V <sub>RRM</sub>	80 V
T <sub>j</sub> (max)	175 °C
V <sub>F</sub> (typ)	490 mV



**Figure 1. Electrical characteristics<sup>(a)</sup>**



# 1 Characteristics

**Table 2. Absolute ratings (limiting values, per diode, at  $T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified)**

Symbol	Parameter				Value	Unit		
$V_{RRM}$	Repetitive peak reverse voltage				80	V		
$I_{F(RMS)}$	Forward rms current				30	A		
$I_{F(AV)}$	Average forward current, $\delta = 0.5$	TO-220AB, I <sup>2</sup> PAK, D <sup>2</sup> PAK	$T_c = 160^{\circ}\text{C}$	Per diode	10	A		
		TO-220FPAB	$T_c = 155^{\circ}\text{C}$	Per device	20			
$I_{FSM}$	Surge non repetitive forward current	$t_p = 10\text{ ms sinusoidal}$		$T_c = 25^{\circ}\text{C}$	220	A		
		$T_j = 25^{\circ}\text{C}, t_p = 1\text{ }\mu\text{s}$			6700			
$V_{ARM}^{(1)}$	Maximum repetitive peak avalanche voltage		$t_p < 1\text{ }\mu\text{s}, T_j < 150^{\circ}\text{C}, I_{AR} < 20.1\text{ A}$		100	V		
$V_{ASM}^{(2)}$	Maximum single pulse peak avalanche voltage	$t_p < 1\text{ }\mu\text{s}, T_j < 150^{\circ}\text{C}, I_{AR} < 20.1\text{ A}$			100	V		
$T_{stg}$	Storage temperature range				-65 to +175	$^{\circ}\text{C}$		
$T_j$	Maximum operating junction temperature <sup>(3)</sup>				175	$^{\circ}\text{C}$		

- For temperature or pulse time duration deratings, please refer to figure 3 and 4. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.
- See
- $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  condition to avoid thermal runaway for a diode on its own heatsink

**Table 3. Thermal parameters**

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220AB I <sup>2</sup> PAK, D <sup>2</sup> PAK	per diode	2.0	$^{\circ}\text{C/W}$
			total	1.10	
	TO-220FPAB	per diode	4.90		
			total	4.05	
$R_{th(c)}$	Coupling	TO-220AB I <sup>2</sup> PAK, D <sup>2</sup> PAK		0.20	$^{\circ}\text{C/W}$
		TO-220FPAB		3.20	

When the two diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

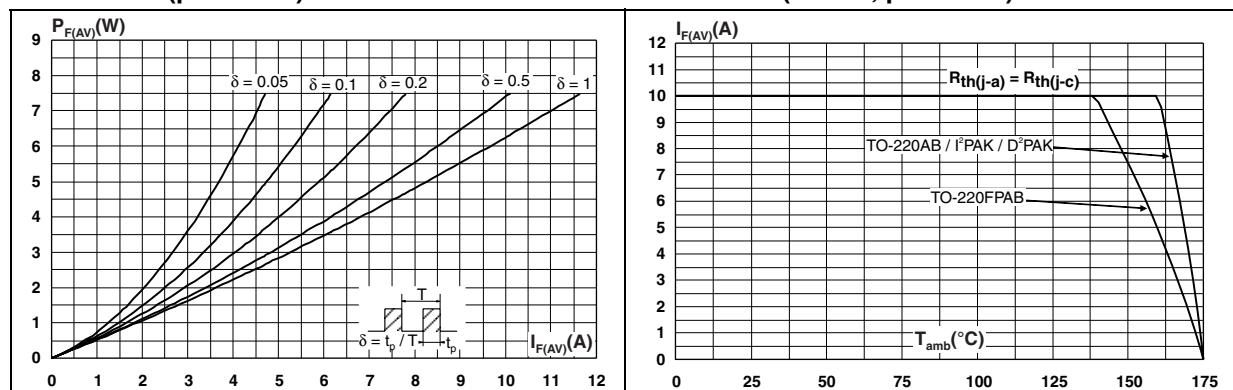
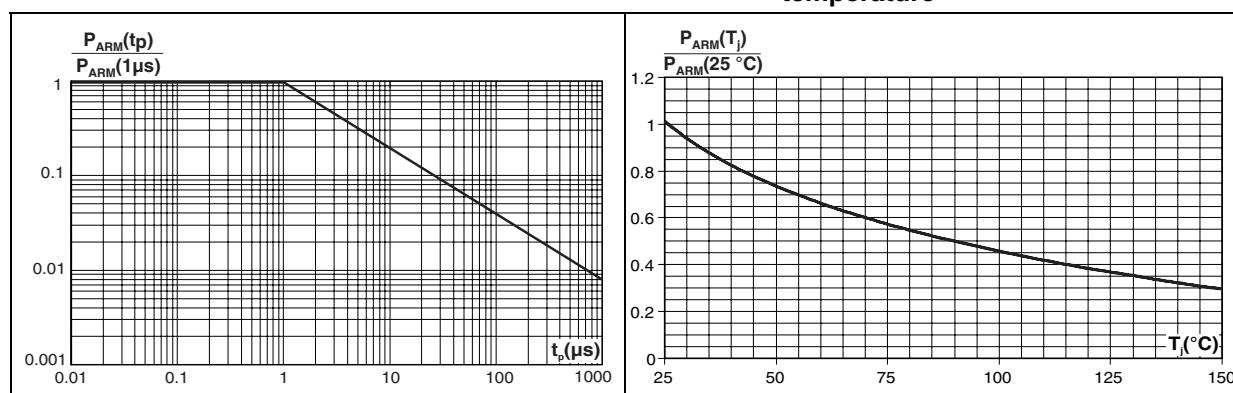
**Table 4. Static electrical characteristics (per diode)**

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$	-	7	30	$\mu\text{A}$
		$T_j = 125^\circ\text{C}$		-	6.2	20	$\text{mA}$
$V_F^{(2)}$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 5 \text{ A}$	-	0.555	0.610	$\text{V}$
		$T_j = 125^\circ\text{C}$		-	0.490	0.530	
		$T_j = 25^\circ\text{C}$	$I_F = 10 \text{ A}$	-	0.670	0.740	
		$T_j = 125^\circ\text{C}$		-	0.575	0.625	
		$T_j = 25^\circ\text{C}$	$I_F = 20 \text{ A}$	-	0.810	0.905	
		$T_j = 125^\circ\text{C}$		-	0.670	0.740	

1. Pulse test:  $t_p = 5 \text{ ms}$ ,  $\delta < 2\%$ 2. Pulse test:  $t_p = 380 \mu\text{s}$ ,  $\delta < 2\%$ 

To evaluate the conduction losses use the following equation:

$$P = 0.51 \times I_{F(AV)} + 0.0115 \times I_F^2 (\text{RMS})$$

**Figure 2. Average forward power dissipation versus average forward current (per diode)****Figure 3. Average forward current versus ambient temperature ( $\delta = 0.5$ , per diode)****Figure 4. Normalized avalanche power derating versus pulse duration****Figure 5. Normalized avalanche power derating versus junction temperature**

### 3 Ordering information

**Table 9. Ordering information**

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS20M80CT	STPS20M80CT	TO-220AB	1.9 g	50	Tube
STPS20M80CFP	STPS20M80CFP	TO-220FPAB	2.0 g	50	Tube
STPS20M80CR	STPS20M80CR	I <sup>2</sup> PAK	1.49 g	50	Tube
STPS20M80CG-TR	STPS20M80CG	D <sup>2</sup> PAK	1.48 g	1000	Tape and reel